

# KA78TXX

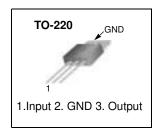
# 3-Terminal 3A Positive Voltage Regulator

### **Features**

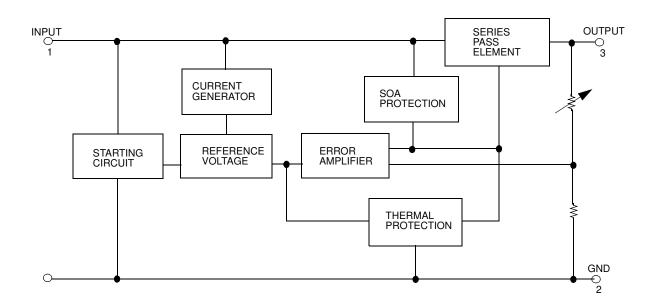
- Output Current in Excess of 3.0A
- Output Transistor Safe Operating Area Compensation
- Power Dissipation: 25W
- Internal Short Circuit Current Limiting
- Internal Thermal Overload Protection
- Output Voltage Offered in 4% Tolerance
- No External Components Required
- Output Voltage of 5, 12 and 15V

### **Description**

This family of fixed voltage regulators are monolithic integrated circuit capable of driving loads in excess of 3.0A.



### **Internal Block Diagram**



## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Input Voltage (for V <sub>O</sub> = 5V to 12V) (for V <sub>O</sub> = 15V)	VI	35 40	<b>&gt;</b>
Power Dissipation	PD	Internally limited	-
Thermal Resistance, Junction to Air (Note1, 2) Ta = +25°C	RθJA	65	°C/W
Thermal Resistance, Junction to Case (Note1) Tc = +25°C	RθJC	2.5	°C/W
Operating Junction Temperature Range	TJ	0 ~ +125	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

#### Note:

- Thermal resistance test board Size: 76.2mm \* 114.3mm \* 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow.

## **Electrical Characteristics(KA78T05)**

(VI = 10V, IO = 3.0 A,  $0^{\circ}$ C  $\leq$  TJ  $\leq$  +125 $^{\circ}$ C, Po  $\leq$  PMAX (Note3), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	5mA ≤ lo ≤ 3.0A, TJ = +25°C 7.3V ≤ VI ≤ 20V, 5mA ≤ lo ≤ 2.0A	4.8 4.75	5.0 5.0	5.2 5.25	٧
Line Regulation (Note4)	ΔVΟ	7.2V ≤ VI ≤ 35V, Io=5mA, TJ = +25°C 7.2V ≤ VI ≤ 35V, Io=1.0A, TJ = +25°C 7.5V ≤ VI ≤ 20V, Io =2.0A, TJ = +25°C 8.0V ≤ VI ≤ 12V, Io =3.0A, TJ = +25°C		3.0	25	mV
Load Regulation (Note4)	ΔVO	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{ TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, $P = 20W$ TA = +25°C	-	0.002	0.03	%Vo/W
Quiescent Current	IQ	$5mA \le lo \le 3.0A, T_J = +25^{\circ}C$ $5mA \le lo \le 3.0A$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$7.2V \le VI \le 35V$ , Io = 5mA $T_J = +25^{\circ}C$ ; $7.5V \le VI \le 20V$ , Io =2.0A; $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz, 8V \le V_I \le 18V, I_0 = 2.0A$ $T_J = +25^{\circ}C$	-	75	-	dB
Dropout Voltage	VD	Io = 3A ,TJ = +25°C	-	2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C, 10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	TA = +25°C	-	5.0	-	Α
Output Resistance	Ro	f = 1.0kHz	-	2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 35V, TJ =+25°C	-	1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔVΟ/ΔΤ	Io = 5.0mA	-	0.2	ı	mV/°C

#### Note:

- 3. Although power dissipation is internally limited, specifications apply only for  $P_O \le P_{max}$ ,  $P_{max} = 25W$
- 4. Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used.

## Electrical Characteristics(KA78T12) (Continued)

(VI = 19V, IO = 3.0 A,  $0^{\circ}$ C  $\leq$  TJ  $\leq$  +125 $^{\circ}$ C, Po  $\leq$  PMAX (Note1), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5mA \le lo \le 3.0A$ , $T_J = +25^{\circ}C$ $14.5V \le VI \le 27V$ , $5mA \le lo \le 2.0A$	11.5 11.4	12 12	12.5 12.8	V
Line Regulation (Note2)	ΔVο	$\begin{array}{l} 14.5 V \leq VI \leq 35 V, \ lo=5 mA, \ T_J = +25^{\circ}C \\ 14.5 V \leq VI \leq 35 V, \ lo=1.0A, \ T_J = +25^{\circ}C \\ 14.9 V \leq VI \leq 28 V, \ lo=2.0A, \ T_J = +25^{\circ}C \\ 16 V \leq VI \leq 22 V, \ lo=3.0A, \ T_J = +25^{\circ}C \end{array}$	-	6.0	45	mV
Load Regulation (Note2)	ΔVO	$5\text{mA} \leq \text{Io} \leq 3.0\text{A}, \ T_J = +25^{\circ}\text{C}$ $5\text{mA} \leq \text{Io} \leq 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C	-	0.002	0.03	%Vo/W
Quiescent Current	IQ	$5\text{mA} \leq \text{lo} \leq 3.0\text{A}, \text{ T}_\text{J} = +25^{\circ}\text{C}$ $5\text{mA} \leq \text{lo} \leq 3.0\text{A}$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$14.5V \le VI \le 35V$ , $Io = 5mA$ $T_J = +25^{\circ}C$ ; $14.9V \le VI \le 27V$ , $Io = 2.0A$ $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz, 15V \le V_I \le 25V, Io = 2.0A$ $T_J = +25^{\circ}C$		67	-	dB
Dropout Voltage	VD	lo = 3A ,T <sub>J</sub> =+25°C	-	2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C$ , $10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	T <sub>A</sub> =+25°C	-	5.0	-	Α
Output Resistance	Ro	f = 1.0kHz	-	2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 35V, TJ =+25°C	-	1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔV <sub>O</sub> /ΔT	lo = 5.0mA	-	0.5	-	mV/°C

#### Note:

<sup>1.</sup> Although power dissipation is internally limited, specifications apply only for Po ≤ Pmax, Pmax = 25W

<sup>2.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. ( PMAX = 25W)

## Electrical Characteristics(KA78T15) (Continued)

(VI = 23V, IO = 3.0A,  $0^{\circ}$ C  $\leq$  TJ  $\leq$  +125 $^{\circ}$ C, Po  $\leq$  PMAX (Note1), unless otherwise specified.)

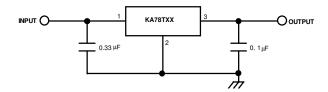
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5mA \le lo \le 3.0A$ , $T_J = +25^{\circ}C$ $17.5V \le VI \le 30V$ , $5mA \le lo \le 2.0A$		15 15	15.6 15.75	V
Line Regulation (Note2)	ΔVο	$\begin{array}{l} 17.6V \leq VI \leq 40V, \ lo=5mA, \ T_J=+25^{\circ}C \\ 17.6V \leq VI \leq 40V, \ lo=1.0A, \ T_J=+25^{\circ}C \\ 18V \leq VI \leq 30V, \ lo=2.0A, \ T_J=+25^{\circ}C \\ 20V \leq VI \leq 26V, \ lo=3.0A, \ T_J=+25^{\circ}C \end{array}$		7.5	55	mV
Load Regulation (Note2)	ΔVO	$5mA \le lo \le 3.0A$ , $T_J = +25^{\circ}C$ $5mA \le lo \le 3.0A$		10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C		0.002	0.03	%Vo/ W
Quiescent Current	IQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$		3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$17.6V \le VI \le 40V$ , $Io = 5mA$ $T_J = +25^{\circ}C$ ; $18V \le VI \le 30V$ , $Io = 2.0A$ ; $5mA \le Io \le 3.0A$ , $T_J = +25^{\circ}C$		0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz, 18.5V \le V_I \le 28.5V, Io = 2.0A$ $T_J = +25^{\circ}C$		65	-	dB
Dropout Voltage	VD	lo = 3A,T <sub>J</sub> =+25°C	-	2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C$ , $10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	T <sub>A</sub> =+25°C	-	5.0	-	Α
Output Resistance	Ro	f = 1.0kHz		2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 40V, TJ =+25°C	-	1.0	2.0	Α
Average Temperature Coefficient of Output Voltage	ΔV <sub>O</sub> /ΔΤ	lo = 5.0mA		0.5	-	mV/°C

#### Note:

<sup>1.</sup> Although power dissipation is internally limited, specifications apply only for Po ≤ Pmax, Pmax = 25W

<sup>2.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. ( PMAX = 25W)

# **Typical Application**



#### Notes:

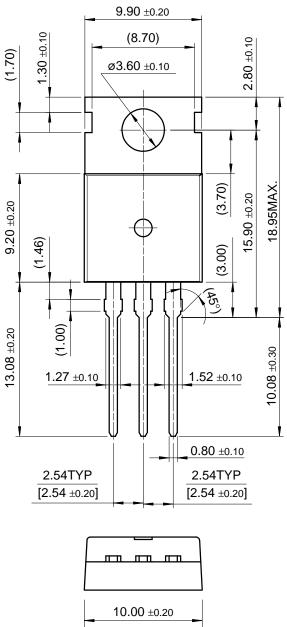
- 1. To specify an output voltage, substitute voltage value for "XX".
- 2. Bypass Capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator

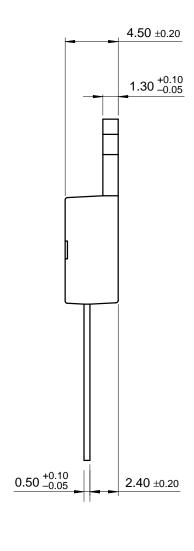
### **Mechanical Dimensions**

### **Package**

### **Dimensions in millimeters**

**TO-220** 





# **Ordering Information**

Product Number	Package	Operating Temperature
KA78T05		
KA78T12	TO-220	0 ~ +125°C
KA78T15		

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